

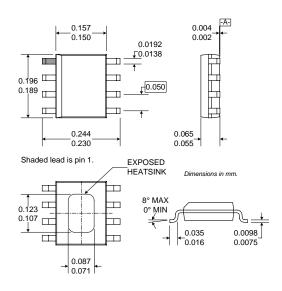
LOW POWER LINEAR AMPLIFIER

Typical Applications

- 2.14GHz UMTS Systems
- Digital Communication Systems
- PCS Communication Systems
- Commercial and Consumer Systems

Product Description

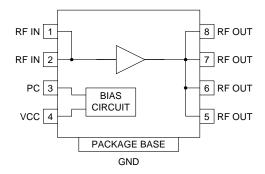
The RF5187 is a highly-linear, low-power amplifier IC. It has been designed for use as the driver RF amplifier in applications such as W-CDMA basestations. The RF5187 requires an input and output matching network and power supply feed line. The device is manufactured on an advanced Gallium Arsenide HBT process, and is packaged in a 8-pin plastic package with a backside ground.



Package Style: SOIC-8 Slug

Optimum Technology Matching® Applied

☐ Si BJT ☐ GaAs MESFET☐ Si Bi-CMOS☐ SiGe HBT☐ Si CMOS☐ InGaP/HBT☐ GaN HEMT☐ SiGe Bi-CMOS☐



Functional Block Diagram

Features

- Single 3V to 6V Supply
- 10dBm to 20dBm Ultra Linear Output Power
- 14dB Gain at 2.14GHz
- Power Down Mode
- 800MHz to 2500MHz Operation

Ordering Information

RF5187 Low Power Linear Amplifier
RF5187 PCBA Fully Assembled Evaluation Board

 RF Micro Devices, Inc.
 Tel (336) 664 1233

 7628 Thorndike Road
 Fax (336) 664 0454

 Greensboro, NC 27409, USA
 http://www.rfmd.com

Rev A3 030409 2-649

RF5187

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{CC})	-0.5 to +7.5	V_{DC}
Power Control Voltage (V _{PC})	-0.5 to +5V	V
DC Supply Current	450	mA
Input RF Power	+20	dBm
Output Load VSWR	20:1	
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +100	°C



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Parameter	Specification		Unit	Condition		
Parameter	Min.	Тур.	Max.	Onit	Condition	
Overall					T=25°C, V _{CC} =5.0V, I _{CC} =240mA, Freq=2140MHz, P _{OUT} =13dBm	
Frequency Range	800		2500	MHz		
Output Power		13		dBm		
OP1dB		29		dBm		
Small Signal Gain	13		15	dB		
Input VSWR		1.5:1			With external matching network.	
Two-Tone Specification						
Output IP3	41	43	45	dBm	13dBm per tone.	
Power Control						
V_{PC}	2.7	3.1	3.7	V	To obtain 240 mA idle current.	
Power Control "OFF"	0.2	0.5		V	Threshold voltage at device input.	
Power Supply						
Power Supply Voltage	5		6	V		
Supply Current			240	mA		
Power Down Current		2	10	μΑ	V _{PC} =0.2V	

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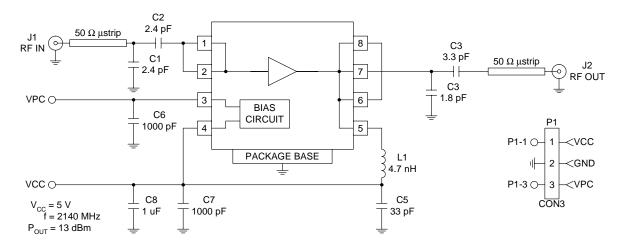
RF5187

Pin	Function	Description	Interface Schematic
1	RF IN	RF input. This input is DC-coupled, so an external blocking capacitor is required if this pin is connected to a DC path. An optimum match to 50Ω is obtained by providing an external series capacitor of 2.4pF and then a shunt capacitor of 2.4pF. Those values are typical for 2140MHz; other values may be required for other frequencies.	
2	RF IN	Same as pin 1.	
3	PC	Power control pin. For obtaining maximum performance, the voltage on this pin can be used to set correct bias level. In a typical application this is implemented by a feedback loop. The feedback can be based on the actual supply current of the device (i.e. maintaining a fixed current level), or it can be based on the RF output power level to maintain a fixed RF power level (Automatic Level Control loop). A voltage of 0.5V or lower brings the part into power down state.	
4	VCC	Power supply pin for the bias circuits. External low frequency bypass capacitors should be connected if no other low frequency decoupling is nearby.	
5	RF OUT	RF output and bias for the output stage. The power supply for the output transistor needs to be supplied to this pin. This can be done through a quarter-wavelength microstrip line that is RF-grounded at the other end, or through an RF inductor that supports the required DC currents. Optimum load impedance is achieved by providing a shunt capacitor of 1.8pF and a series capacitor of 3.3pF. Those values are typical for 2140 MHz; other values may be required for other frequencies. Since there are several output pins available (which are internally connected), one pin can be used for connecting the bias, another for connecting a (third) harmonic trap filter, and the other pins for the RF output.	
6	RF OUT	Same as pin 5.	
7	RF OUT	Same as pin 5.	
8	RF OUT	Same as pin 5.	
Pkg Base	GND	Ground connection. The backside of the package should be connected to the ground plane through a short path (i.e., vias under the device may be required).	

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Evaluation Board Schematic 2140MHz Operation

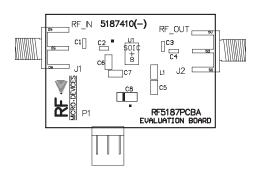
(Download <u>Bill of Materials</u> from www.rfmd.com.)

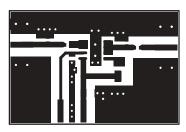


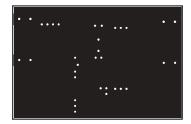
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Evaluation Board Layout Board Size 1.5" x 1.0"

Board Thickness 0.031", Board Material FR-4







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